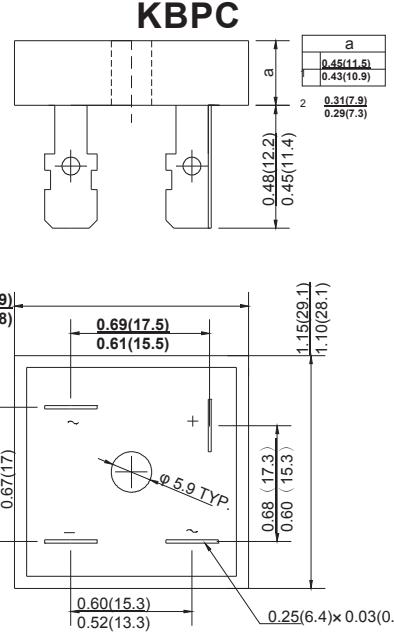


SILICON BRIDGE RECTIFIER
REVERSE VOLTAGE : 50 --- 1000 V CURRENT: 35.0 A
FEATURES

- Rating to 1000V PRV
- Surge overload rating to 400Amperes peak Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product Lead solderable per MIL-STD-202 method 208
- High case dielectric with standing voltage of 2500 VRMS
- High efficiency

MECHANICAL DATA

- Case style: KBPC plastic molded
- Mounting: thru hole for # 8 screw mounting



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted) Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate by 20%.

		KBPC 35005	KBPC 3501	KBPC 3502	KBPC 3504	KBPC 3506	KBPC 3508	KBPC 3510	UNITS
Maximum recurrent peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward output current @T _A =25°C	I _{F(AV)}	35.0						A	
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	I _{FSM}	400.0						A	
Maximum instantaneous forward voltage @ 17.5 A	V _F	1.1						V	
Maximum reverse current @T _A =25°C at rated DC blocking voltage @T _A =100°C	I _R	10.0 1.0						μA mA	
Operating junction temperature range	T _J	- 55 ---- + 125						°C	
Storage temperature range	T _{STG}	- 55 ---- + 150						°C	



RATINGS AND CHARACTERISTIC CURVES

FIG.1 – PEAK FORWARD SURGE CURRENT

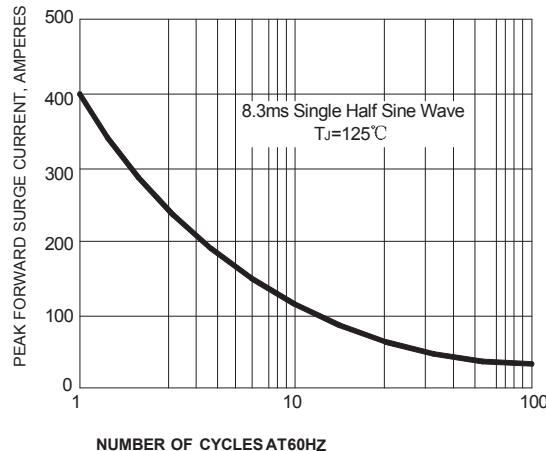


FIG.2 – FORWARD DERATING CURVE

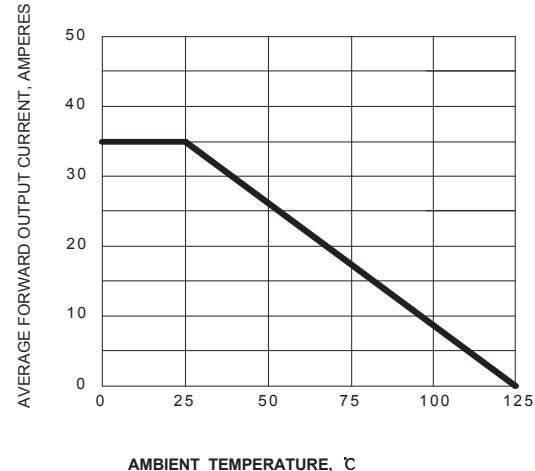


FIG.3 – TYPICAL FORWARD CHARACTERISTIC

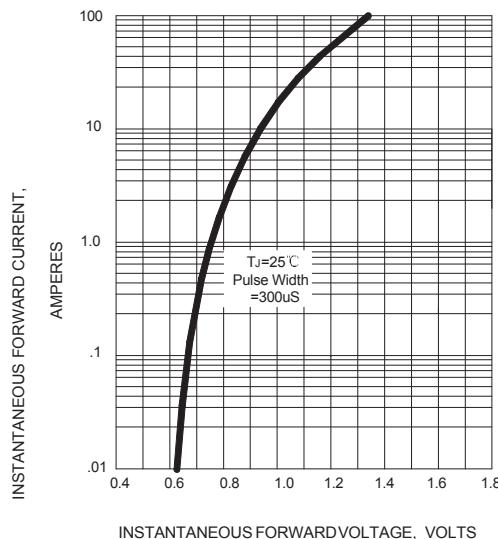


FIG.4 – TYPICAL REVERSE CHARACTERISTIC

